



v03.0705

HMC346LP3 / 346LP3E

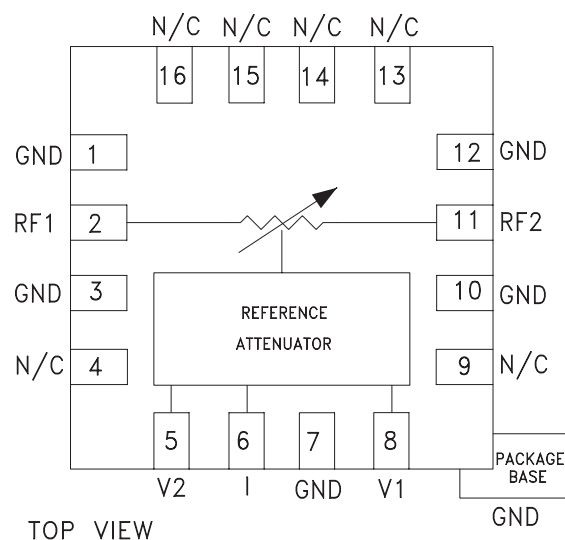
GaAs MMIC VOLTAGE-VARIABLE ATTENUATOR, DC - 14 GHz

Typical Applications

The HMC346LP3 / HMC346LP3E is ideal for:

- Basestation Infrastructure
- Fiber Optics & Broadband Telecom
- Microwave Radio & VSAT
- Military Radios, Radar, & ECM
- Test Instrumentation

Functional Diagram



Features

- Wide Bandwidth: DC - 14 GHz
- Low Phase Shift vs. Attenuation
- 30 dB Attenuation Range
- Simplified Voltage Control
- 3 mm x 3 mm x 1 mm SMT Package

General Description

The HMC346LP3 & HMC346LP3E are pabsorp-tive Voltage Variable Attenuators (VVA) in low cost leadless surface mount plastic packages operating from DC - 14 GHz. It features an on-chip reference attenuator for use with an external op-amp to provide simple single voltage attenuation control, 0 to -3V. The device is ideal in designs where an analog DC control signal must control RF signal levels over a 30 dB amplitude range. This VVA is an excellent alterna-tive to the HMC121C8.

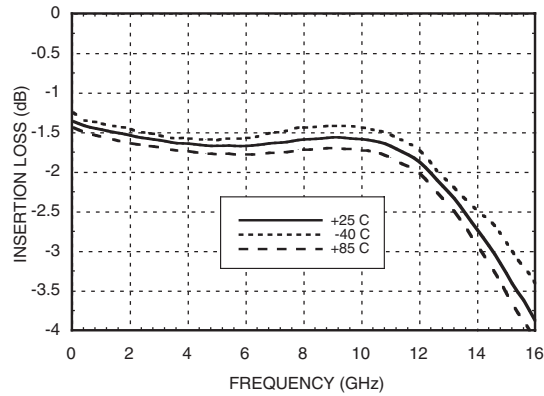
Electrical Specifications, $T_A = +25^\circ \text{C}$, 50 ohm system

Parameter		Min	Typical	Max	Units
Insertion Loss	DC - 10 GHz		1.7	2.2	dB
	DC - 14 GHz		2.8	3.3	dB
Attenuation Range	DC - 10 GHz	27	30		dB
	DC - 14 GHz	22	27		dB
Return Loss	DC - 14 GHz	5	10		dB
Switching Characteristics	tRISE, tFALL (10/90% RF):		2		ns
	tON, tOFF (50% CTL to 10/90% RF):		8		ns
Input Power for 0.25 dB Compression (0.5 - 8 GHz)	Min. Atten:		+8		dBm
	Atten. >2 dB:		-4		dBm
Input Third Order Intercept (0.5 - 8 GHz) (Two-tone Input Power = -8 dBm Each Tone)	Min. Atten:		+25		dBm
	Atten. >2 dB:		+10		dBm

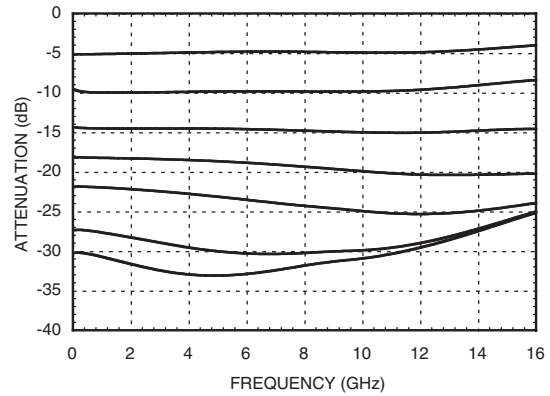
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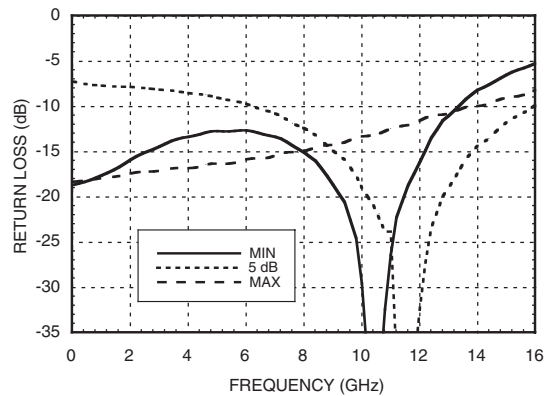
Insertion Loss vs. Temperature



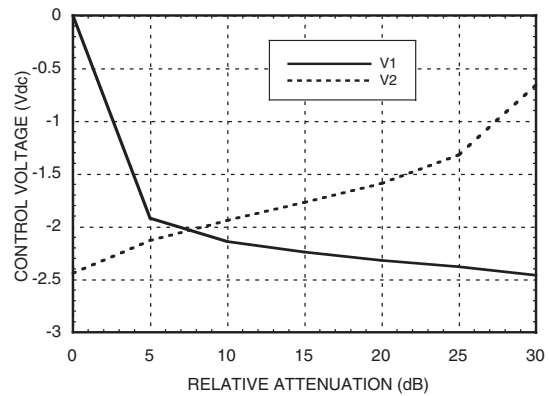
Relative Attenuation



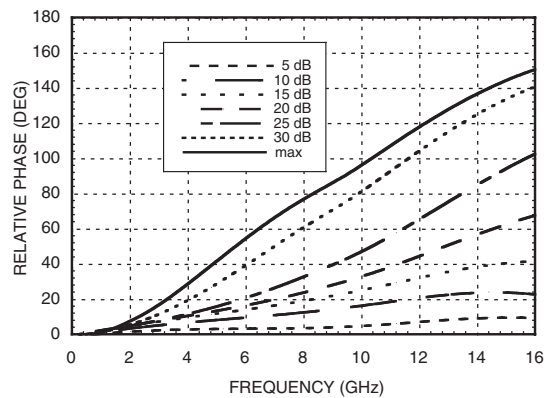
Return Loss vs. Attenuation



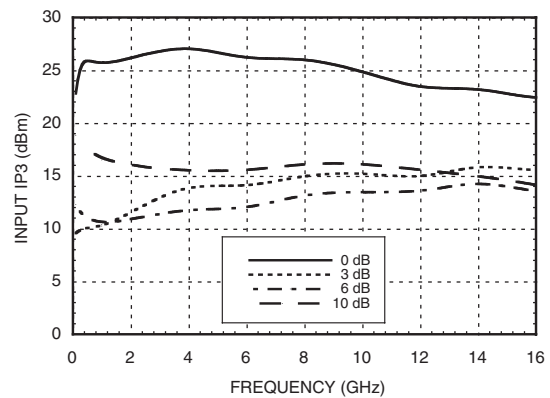
**Relative Attenuation vs.
Control Voltage @ 10 GHz**



Relative Phase



Input IP3 vs. Attenuation*

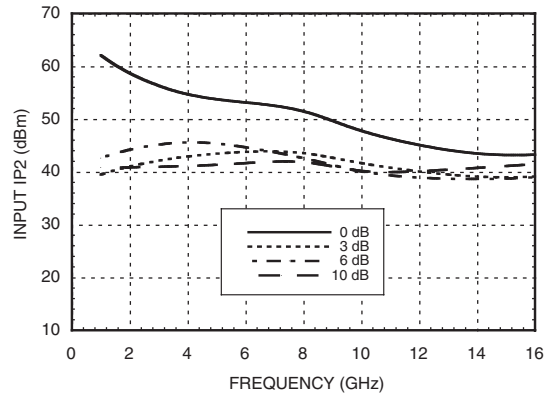


*Two-tone input power = -8 dBm each tone, 1 MHz spacing.

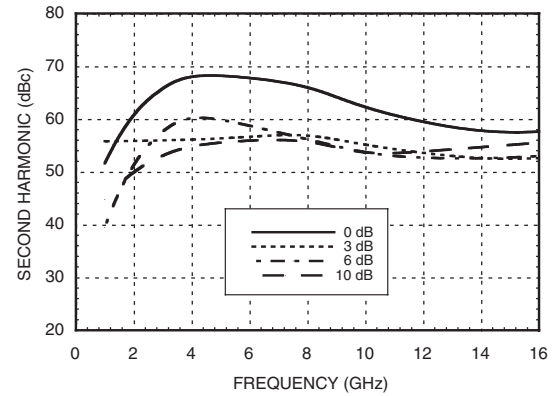
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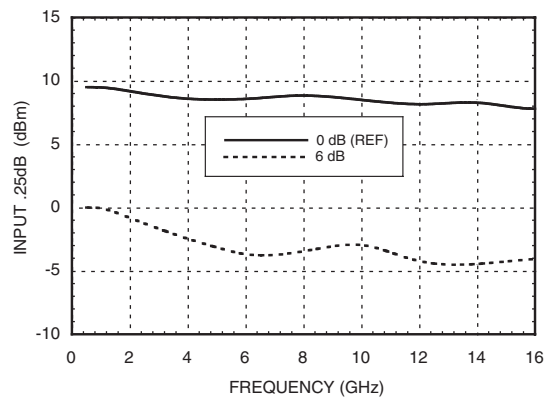
Input IP2 vs. Attenuation*



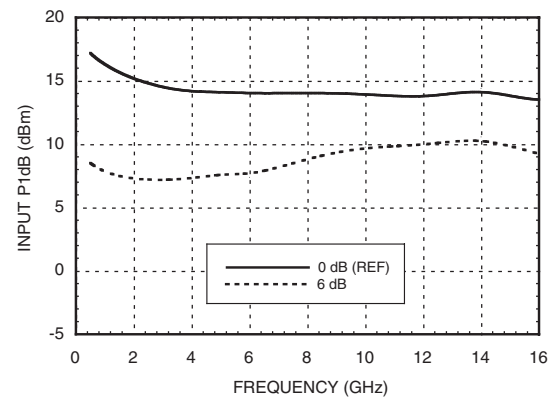
Second Harmonic vs. Attenuation, Pin = -8 dBm



0.25 dB Compression vs. Attenuation



1 dB Compression vs. Attenuation



*Two-tone input power = -8 dBm each tone, 1 MHz spacing.



MICROWAVE CORPORATION

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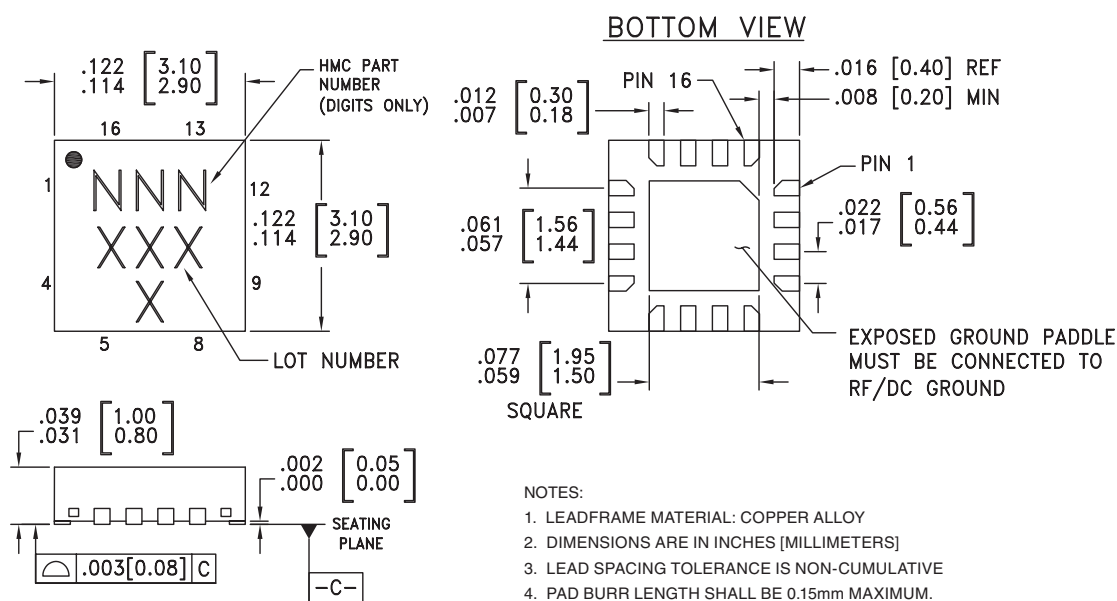
Absolute Maximum Ratings

RF Input Power	+18 dBm
Control Voltage Range	+1.0 to -5.0 Vdc
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC346LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	346 XXXX
HMC346LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	346 XXXX

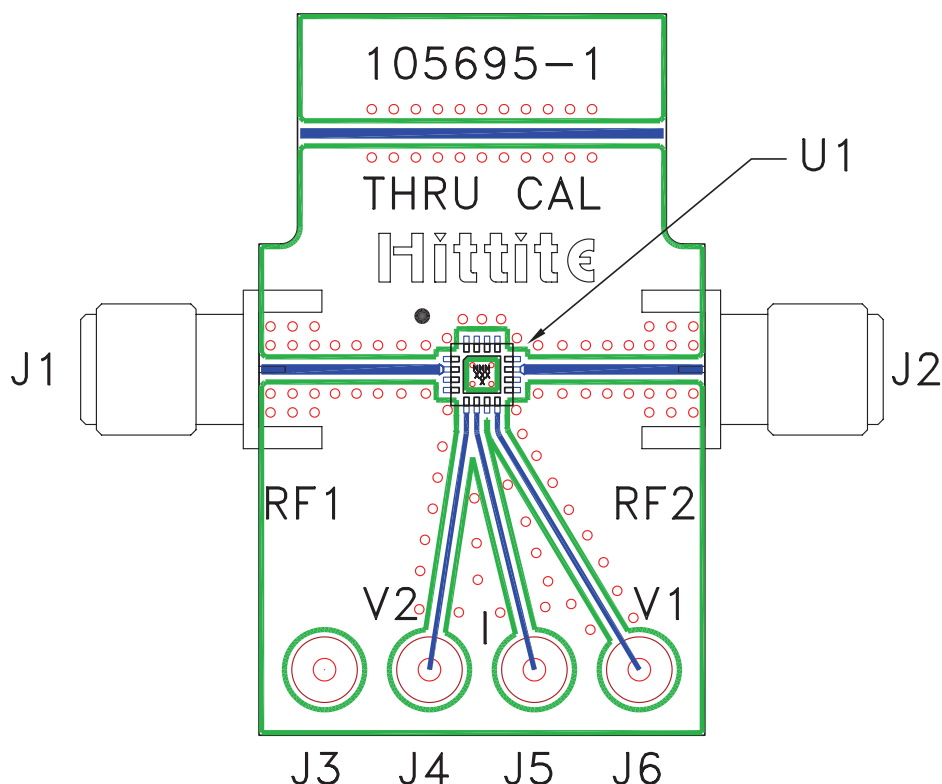
[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
Order On-line at www.hittite.com

Evaluation PCB



List of Materials for Evaluation PCB 105709 [1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3 - J6	DC Pin
U1	HMC346LP3 / HMC346LP3E VVA
PCB [2]	105695 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF ports should be 50 ohm impedance and the package ground leads and package bottom should be connected directly to the PCB RF ground plane, similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.